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FORM PTO 1449 (modified) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE LIST OF REFERENCES CITED BY APPLICANT(S) (Use several sheets if necessary)				ATTY DOCKET NO. 03500.017975	APPLICAT N PCT/JF 3/24/04	APPLICATION NO. National. Phase of PCT/JP2004/004072 filed 3/24/04] [
				APPLICANT SHUNICHI ISHIHARA				
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/X.T./	JP	3-228324	10/09/91	Japan	H01L	21/208	Abstract	
/X.T./	JP	2001-217442A	08/10/01	Japan	H01L	31/04	Abstract	
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/X.T./		"Investigation of Polycrystalline Silicon Deposition on Glass Substrates", Zhengrong Shi et al., Solar Energy Materials and Solar Cells 31 (1993) 51-60, Holland, pgs. 51-60						
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Oraw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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